

گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما

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برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش
 تک فاز و 3 فاز
 - آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
 - آموزش تخصصی ابراز آلات شارژی



IMPORTANT NOTICE

10 December 2015

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

WWW - For www.nxp.com use www.ween-semi.com

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If you have any questions related to this document, please contact our nearest sales office via e- mail or phone (details via <u>salesaddresses@ween-semi.com</u>).

Thank you for your cooperation and understanding, WeEn

Semiconductors



DISCRETE SEMICONDUCTORS



Product specification

March 1997



Product specification

BT152 series

GENERAL DESCRIPTION

Glass passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

PINNING - TO220AB

PIN	DESCRIPTION			
1	cathode			
2	anode			
3	gate			
tab	anode			

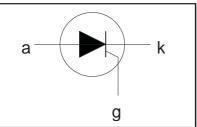
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BT152-	400R	600R	800R	
V _{DRM} ,	Repetitive peak off-state	450	650	800	V
V _{RRM}	voltages				
I _{T(AV)}	Average on-state current	13	13	13	А
I _{T(RMS)}	RMS on-state current	20	20	20	А
I _{TSM}	Non-repetitive peak on-state	200	200	200	А
	current				

PIN CONFIGURATION

tab

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{drm}	Repetitive peak off-state voltages		-	-400R 450 ¹	-600R 650 ¹	-800R 800	V
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 103$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		13 20		A A
		t = 10 ms t = 8.3 ms	-		200 220		A A
l ² t	I ² t for fusing	t = 10 ms	-		200		A ² s
dl⊤/dt	Repetitive rate of rise of on-state current after triggering	$ I_{TM} = 50 \text{ A}; I_G = 0.2 \text{ A}; \\ dI_G/dt = 0.2 \text{ A}/\mu s $	-		200		A/μs
I _{GM}	Peak gate current		-		5 5		А
V _{GM}	Peak gate voltage		-				V
V _{RGM}	Peak reverse gate voltage		-		5		V
P _{GM}	Peak gate power		-		20		W
P _{G(AV)}	Average gate power	over any 20 ms period	-		0.5		W
T _{stg} Tj	Storage temperature Operating junction temperature		-40 -		150 125		С° С

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

BT152 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R_{thj-mb}	Thermal resistance junction to mounting base		-	-	1.1	K/W
R_{thj-a}	Thermal resistance junction to ambient	in free air	-	60	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

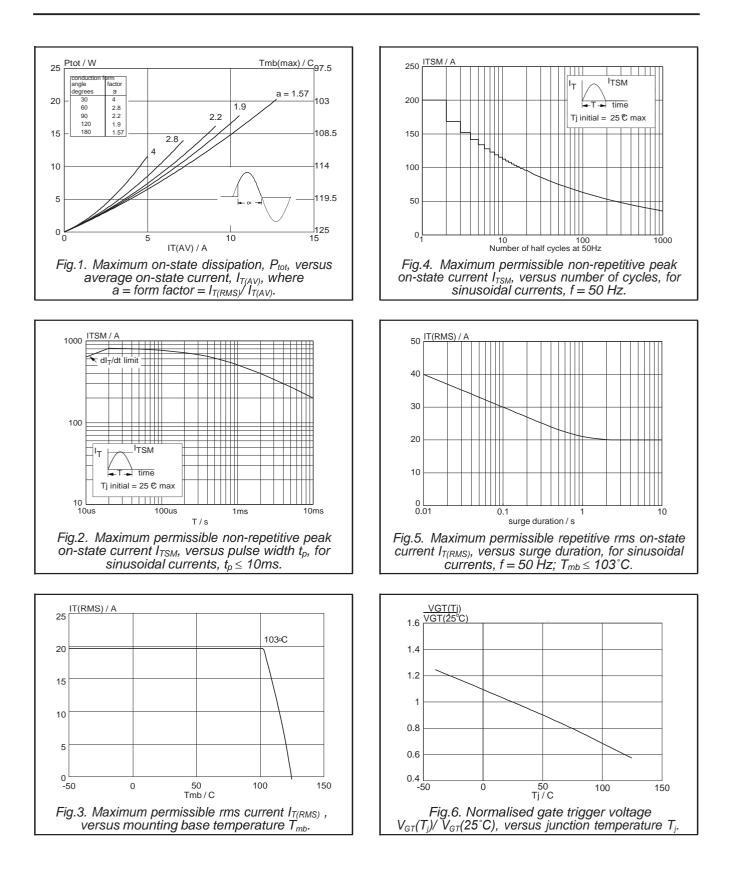
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$	-	3	32	mA
IL.	Latching current	$V_D = 12 V; I_{GT} = 0.1 A$	-	25	80	mA
Ін	Holding current	$V_D = 12 V$; $I_{GT} = 0.1 A$	-	15	60	mA
V _T	On-state voltage	$I_{T} = 40 \text{ A}$	-	1.4	1.75	V
V _{GT}	Gate trigger voltage	$V_D = 12 V; I_T = 0.1 A$	-	0.6	1.5	V
0.		$V_D = V_{DRM(max)}; I_T = 0.1 \text{ A}; T_j = 125 \degree \text{C}$	0.25	0.4	-	V
I _D , I _R	Off-state leakage current		-	0.2	1.0	mA
D, K	Ŭ	$V_D = V_{DRM(max)}; V_R = V_{RRM(max)}; I_j = 125 ^{\circ}C$				

DYNAMIC CHARACTERISTICS

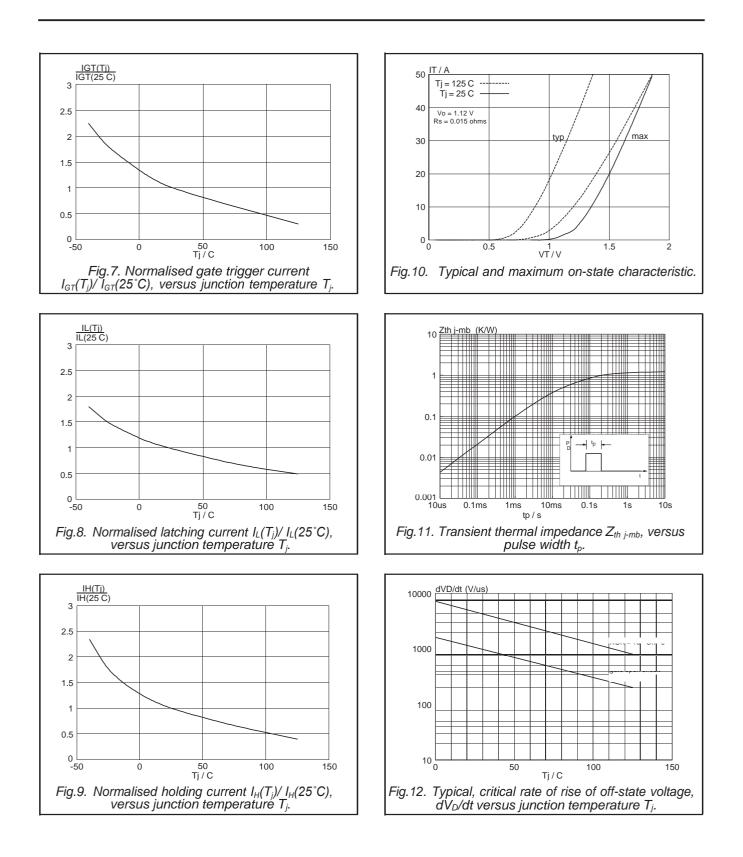
 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform gate open circuit	200	300	-	V/µs
t _{gt}	Gate controlled turn-on time	$V_D = V_{DRM(max)}; I_G = 0.1 \text{ Å}; dI_G/dt = 5 \text{ A}/\mu\text{s};$	-	2	-	μS
t _q	Circuit commutated turn-off time	$\begin{array}{l} I_{TM} = 40 \text{ A} \\ V_D = 67\% \text{ V}_{DRM(max)}; T_j = 125 ^\circ\text{C}; \\ I_{TM} = 50 \text{ A}; V_R = 25 V; dI_{TM}/dt = 30 A/\mu\text{s}; \\ dV_D/dt = 50 V/\mu\text{s}; R_{GK} = 100 \Lambda \end{array}$	-	70	-	μS

BT152 series

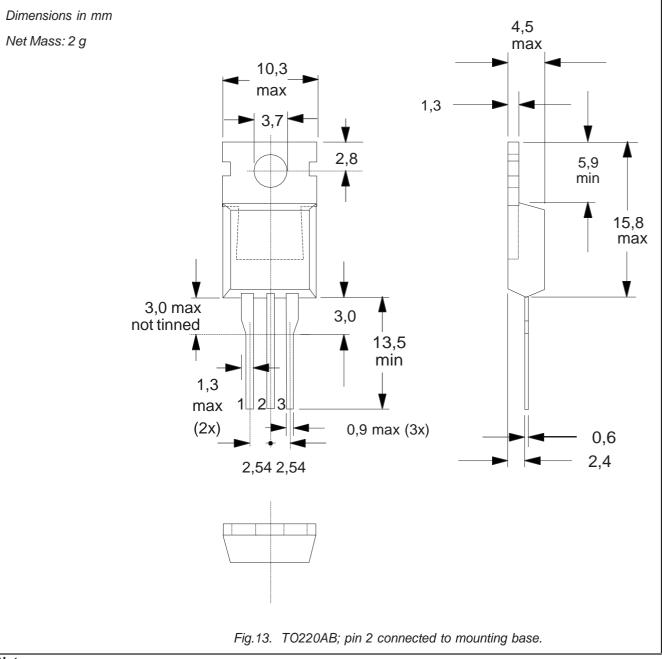


BT152 series



BT152 series

MECHANICAL DATA



Notes

1. Refer to mounting instructions for TO220 envelopes.

2. Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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